

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET EFC4615R — General-Purpose Switching Device **Applications**

Features

- 2.5V drive
- · Best suited for LiB charging and discharging switch
- · Common-drain type

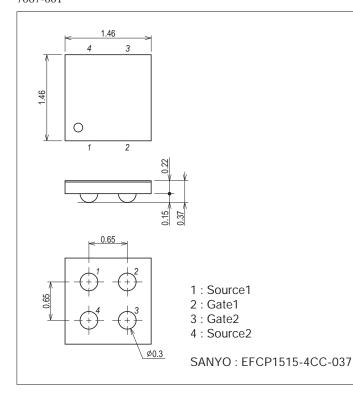
Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|--------------------------|--------|--|-------------|------|
| Source-to-Source Voltage | VSSS | | 24 | V |
| Gate-to-Source Voltage | VGSS | | ±12 | V |
| Source Current (DC) | IS | | 6 | Α |
| Source Current (Pulse) | ISP | PW≤10μs, duty cycle≤1% | 60 | A |
| Total Dissipation | PT | When mounted on ceramic substrate (5000mm ² x0.8mm) | 1.6 | W |
| Channel Temperature | Tch | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Package Dimensions

unit : mm (typ) 7067-001



Product & Package Information

- : EFCP
- JEITA, JEDEC : -

• Minimum Packing Quantity : 5,000 pcs./reel

Taping Type : TR

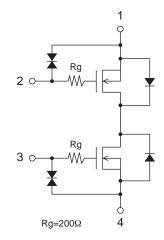
• Package

 \overline{O} \cap



Marking

Electrical Connection



SANYO Semiconductor Co., Ltd. http://semicon.sanyo.com/en/network

Electrical Characteristics at Ta=25°C

| Deneration | Symbol | Conditions | | Ratings | | | 11.2 |
|---|-----------------------|---|----------------|---------|-----|-----|------|
| Parameter | | | | min | typ | max | Unit |
| Source-to-Source Breakdown Voltage | V(BR)SSS | IS=1mA, VGS=0V | Test Circuit 1 | 24 | | | V |
| Zero-Gate Voltage Source Current | ISSS | VSS=20V, VGS=0V | Test Circuit 1 | | | 1 | μΑ |
| Gate-to-Source Leakage Current | IGSS | VGS=±8V, VSS=0V | Test Circuit 2 | | | ±10 | μΑ |
| Cutoff Voltage | VGS(off) | V _{SS} =10V, I _S =1mA | Test Circuit 3 | 0.5 | | 1.3 | V |
| Forward Transfer Admittance | yfs | VSS=10V, IS=3A | Test Circuit 4 | | 5.4 | | S |
| Static Source-to-Source On-State Resistance | R _{SS} (on)1 | IS=3A, VGS=4.5V | Test Circuit 5 | 19 | 27 | 31 | mΩ |
| | R _{SS} (on)2 | IS=3A, VGS=4.0V | Test Circuit 5 | 21 | 28 | 33 | mΩ |
| | R _{SS} (on)3 | IS=3A, VGS=3.1V | Test Circuit 5 | 24 | 33 | 44 | mΩ |
| | RSS(on)4 | IS=3A, VGS=2.5V | Test Circuit 5 | 28 | 39 | 52 | mΩ |
| Turn-ON Delay Time | t _d (on) | See specified Test Circuit. | Test Circuit 7 | | 13 | | ns |
| Rise Time | tr | See specified Test Circuit. | Test Circuit 7 | | 235 | | ns |
| Turn-OFF Delay Time | t _d (off) | See specified Test Circuit. | Test Circuit 7 | | 335 | | ns |
| Fall Time | tf | See specified Test Circuit. | Test Circuit 7 | | 360 | | ns |
| Total Gate Charge | Qg | VSS=10V, VGS=4.5V, IS=6A | | | 8.8 | | nC |
| Forward Source-to-Source Voltage | V _F (S-S) | IS=6A, VGS=0V | Test Circuit 6 | | 1 | 1.2 | V |

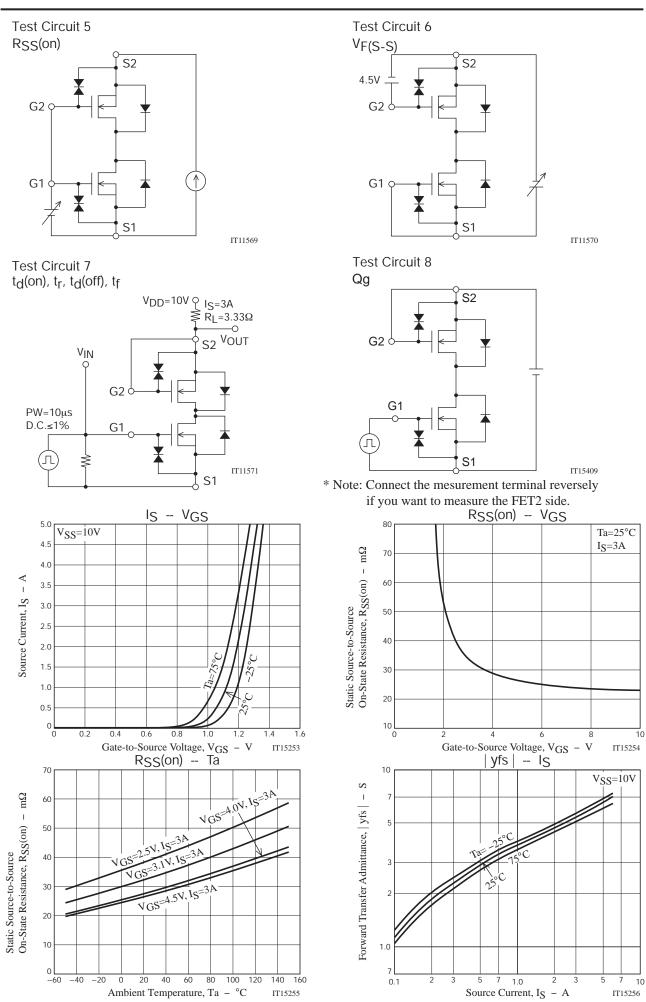
Test circuits are example of measuring FET1 side

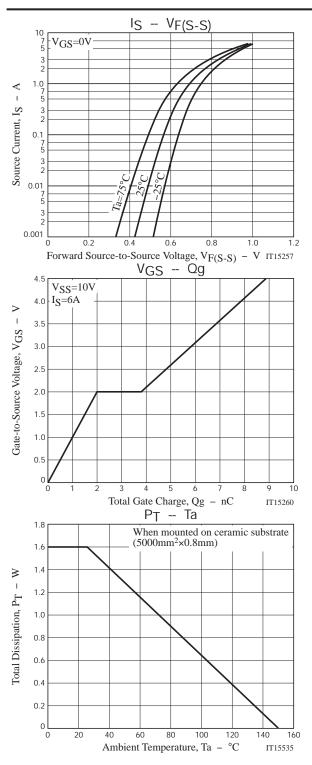
Test Circuit 1 Test Circuit 2 VSSS / ISSS IGSS(+) / (--) S2 S2 G2 G2 G1 (G1 S1 S1 IT11565 IT11566 Test Circuit 3 Test Circuit 4 VGS(off) | yfs | S2 S2 G2 G2 10V 1mA G1 G1 S1 S1

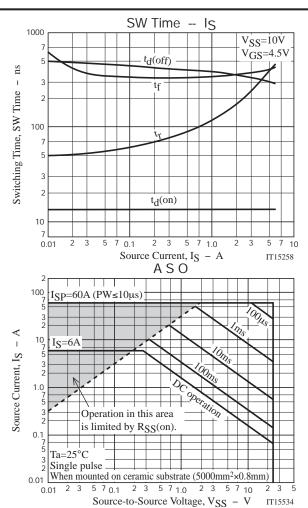
IT11567

* Note: Connect the mesurement terminal reversely if you want to measure the FET2 side.

IT11568







Note on usage : Since the EFC4615R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of June, 2010. Specifications and information herein are subject to change without notice.